

### Features

- Max  $r_{DS(on)} = 0.5 \Omega$  at  $V_{GS} = 4.5 V$ ,  $I_D = -0.83 A$
- Max  $r_{DS(on)} = 0.7 \Omega$  at  $V_{GS} = 2.5 V$ ,  $I_D = -0.70 A$
- Max  $r_{DS(on)} = 1.2 \Omega$  at  $V_{GS} = 1.8 V$ ,  $I_D = -0.43 A$
- Max r<sub>DS(on)</sub> = 1.8 Ω at V<sub>GS</sub> = 1.5 V, I<sub>D</sub> = -0.36 A
- Control MOSFET (Q1) includes Zener protection for ESD ruggedness (>4 kV Human body model)
- High performance trench technology for extremely low r<sub>DS(on)</sub>
- Compact industry standard SC89-6 surface mount package
- RoHS Compliant

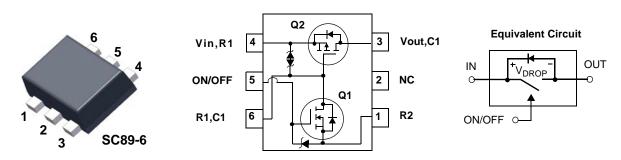


#### **General Description**

This device is particularly suited for compact power management in portable electronic equipment where 2.5 V to 8 V input and 0.83 A output current capability are needed. This load switch integrates a small N-Channel power MOSFET (Q1) that drives a large P-Channel power MOSFET (Q2) in one tiny SC89-6 package.

### Applications

- Power management
- Load switch



#### See Application Circuit

## MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V <sub>IN</sub>	Gate to Source Voltage (Q2)		±8	V
V <sub>ON/OFF</sub>	Gate to Source Voltage (Q1)		-0.5 to 8	V
	Load Current -Continuous	(Note 2)	0.83	^
Load	-Pulsed	(Note 2)	1.0	- A
P <sub>D</sub>	Power Dissipation	(Note 1a)	0.625	w
	Power Dissipation	(Note 1b)	0.446	vv
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C

#### **Thermal Characteristics**

$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	200	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	280	°C/vv

#### **Package Marking and Ordering Information**

Device Marking	Device Packag		Reel Size	Tape Width	Quantity	
Н	FDY6342L	SC89-6	7 "	8 mm	3000 units	

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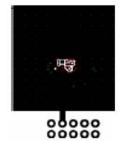
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BVIN	V <sub>IN</sub> Breakdown Voltage	$I_D = -250 \ \mu A$ , $V_{ON/OFF} = 0 \ V$	8			V
I <sub>Load</sub>	Zero Gate Voltage Drain Current	$V_{IN} = -6.4 \text{ V}, V_{ON/OFF} = 0 \text{ V}$			-1	μΑ
I <sub>FL</sub>	Leakage Current, Forward	V <sub>IN</sub> = 8 V, V <sub>ON/OFF</sub> = 0 V			10	μA
I <sub>RL</sub>	Leakage Current, Reverse	$V_{IN} = -8 V, V_{ON/OFF} = 0 V$			-10	μA
	ncteristics (note 2)			I		1
V <sub>ON/OFF(th)</sub>	Gate Threshold Voltage	$V_{IN} = V_{ON/OFF}, I_D = -250 \ \mu A$	0.65	0.85	1.5	V
r <sub>DS(on)</sub>	Static Drain to Source On Resistance (Q2)	V <sub>IN</sub> = 4.5 V, I <sub>D</sub> = -0.83 A		0.28	0.5	Ω
		$V_{IN} = 2.5 \text{ V}, I_D = -0.70 \text{ A}$		0.35	0.7	
		V <sub>IN</sub> = 1.8 V, I <sub>D</sub> = -0.43 A		0.45	1.2	
		$V_{-1} = 1 = V_{-1} = 0.26 $		0.57	1.8	
20(01)		V <sub>IN</sub> = 1.5 V, I <sub>D</sub> = -0.36 A		0.07	1.0	
20(01)	Static Drain to Source On Resistance (Q1)	$V_{IN} = 4.5 \text{ V}, I_D = 0.4 \text{ A}$		2.9	4.0	Ω

### **Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current			-0.25	А
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{ON/OFF} = 0 V$ , $I_S = -0.25 A$ (Note 2)	-0.8	-1.2	V

NOTES:

1. R<sub>0JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design.

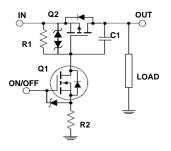


a)200 <sup>o</sup>C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.

b)280 <sup>o</sup>C/W when mounted on a minimum pad of 2 oz copper.

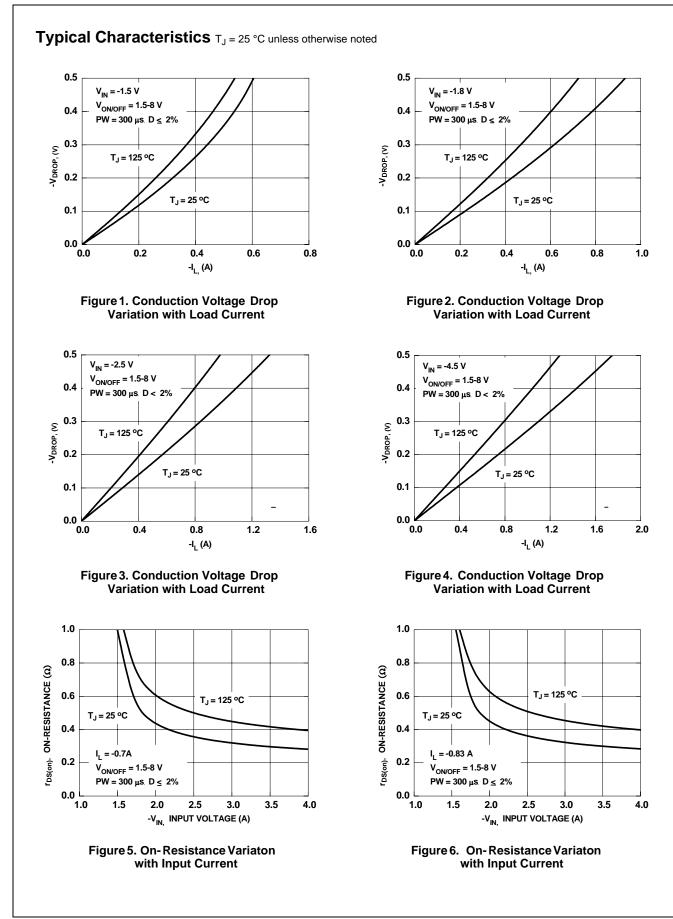
# 2. Pulse Test: Pulse Width < 300 µs, Duty cycle < 2.0%.

## FDY6342L Load Switch Application circuit



#### **External Component Recommendation:**

For additional in-rush current control, R2 and C1 can be added. For more information, see application note AN1030



**Dimensional Outline and Pad Layout** 1.70 А 1.50 в 42 1.30 1.70 1.10 1.50 0.1 C B A 0.30 0.72 (0.20) 0.50 0.50 0.50 LAND PATTERN RECOMMENDATION TOP VIEW 0.60 0.50 С SEATING PLANE 0.00 0.10 0.20 0.08 NOTES: UNLESS OTHERWISE SPECIFIED. 0.05 C REFERENCE TO JEDEC MO293. B. ALL DIMENSIONS ARE IN MILLIMETERS. DOES NOT COMPLY JEDEC STANDARD VALUE. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSION D 0.46 F DIMENSION AND TOLERANCE AS PER ASME F. DRAWING FILE NAME: MAD06A REV3
G. LANDPATTERN RECOMMENDATION GENERATED WITH IPC LANDPATTERN GENERATOR 0.20 0.31 0.15 FAIROHILD ... ⊕0.10 M C A B BOTTOM VIEW ⊕0.05(M) С Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products. Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: https://www.fairchildsemi.com/evaluate/package-specifications/packageDetails.html?id=PN\_NMADA-006

FDY6342L Integrated Load Switch



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Rev. 172